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Attorney's Docket No.: 07977-290001 / US5432

## Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

## Listing of Claims:

Claim 1 (Currently Amended): A light emitting device comprising:

a thin film transistor over a substrate;

an interlayer insulating film over the thin film transistor; and

a capacitor storage over the interlayer insulating film,

wherein the capacitor storage has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode of the thin film transistor,

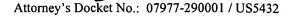
wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor.

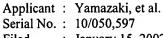
Claim 2 (Currently Amended): A light emitting device as claimed in any one of claim 1, wherein the insulating film is formed by anodization.

Claim 3 (Currently Amended): A light emitting device as claimed in any one of claims claim 1, wherein the connection capacitance wiring line and [[the]] a pixel electrode are formed from the same conductive film.

Claim 4 (Original): An electric appliance comprising the light emitting device according to claim 1, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile

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computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 5 (Currently Amended): A light emitting device comprising:

a thin film transistor over a substrate;

an interlayer insulating film over the thin film transistor; and

a capacitor storage over the interlayer insulating film,

wherein the capacitor storage has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode of the thin film transistor,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor, and

wherein the connection wiring line overlaps an active layer of the thin film transistor.

Claim 6 (Currently Amended): A light emitting device as claimed in any one of claim 5, wherein the insulating film is formed by anodization.

Claim 7 (Currently Amended): A light emitting device as claimed in any one of claim 5, wherein the connection capacitance wiring line and [[the]] a pixel electrode are formed from the same conductive film.

Claim 8 (Original): An electric appliance comprising the light emitting device according to claim 5, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.



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Claim 9 (Original): A light emitting device comprising a thin film transistor, a capacitor storage, and an organic light emitting diode,

wherein the capacitor storage has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode of the thin film transistor, the capacitance wiring line being formed on the same interlayer insulating film on which a pixel electrode of the organic light emitting diode is formed,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor.

Claim 10 (Currently Amended): A light emitting device as claimed in any one of claim 9, wherein the insulating film is formed by anodization.

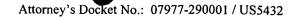
Claim 11 (Currently Amended): A light emitting device as claimed in any one of claim 9, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

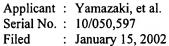
Claim 12 (Original): An electric appliance comprising the light emitting device according to claim 9, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 13 (Original): A light emitting device comprising a thin film transistor, a capacitor storage, and an organic light emitting diode,

wherein the capacitor storage has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode







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of the thin film transistor, the capacitance wiring line being formed on the same interlayer insulating film on which a pixel electrode of the organic light emitting diode is formed,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor,

wherein the luminance of the organic light emitting diode is controlled by an analog video signal.

Claim 14 (Currently Amended): A light emitting device as claimed in any one of claim 13, wherein the insulating film is formed by anodization.

Claim 15 (Currently Amended): A light emitting device as claimed in any one of claim 13, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 16 (Original): An electric appliance comprising the light emitting device according to claim 13, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

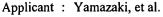
Claim 17 (Currently Amended): A light emitting device comprising:

a source line, a power supply line, a switching thin film transistor, a driving thin film transistor formed over a substrate,

an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, and the driving thin film transistor,

a capacitor storage <u>over the interlayer insulating film</u>, and an organic light emitting diode <u>over the interlayer insulating film</u>,





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wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

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wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the capacitor storage has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line.

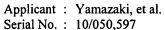
Claim 18 (Currently Amended): A light emitting device as claimed in any one of claim 17, wherein the insulating film is formed by anodization.

Claim 19 (Currently Amended): A light emitting device as claimed in any one of claim 17, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 20 (Original): An electric appliance comprising the light emitting device according to claim 17, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 21 (Currently Amended): A light emitting device having comprising:
a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, and an organic light emitting diode over a substrate,





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## a second capacitor storage over the first capacitor storage,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first capacitor storage has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer, and

wherein the <u>second</u> capacitor storage has the capacitance electrode, the power supply line, and [[an]] <u>second</u> insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor.

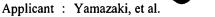
Claim 22 (Currently Amended): A light emitting device as claimed in any one of claim 21, wherein the insulating film is formed by anodization.

Claim 23 (Canceled)

Claim 24 (Original): An electric appliance comprising the light emitting device according to claim 21, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 25 (Currently Amended): A light emitting device having comprising:





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a source line, a power supply line, a switching thin film transistor, <u>and</u> a driving thin film transistor <u>over a substrate</u>,

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an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, and the driving thin film transistor,

a capacitor storage <u>over the interlayer insulating film</u>, and an organic light emitting diode over the interlayer insulating film,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

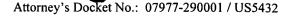
wherein the capacitor storage has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, and

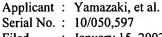
wherein the connection wiring line overlaps an active layer of the switching thin film transistor.

Claim 26 (Currently Amended): A light emitting device as claimed in any one of claim 25, wherein the insulating film is formed by anodization.

Claim 27 (Currently Amended): A light emitting device as claimed in any one of claim 25, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.







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Claim 28 (Original): An electric appliance comprising the light emitting device according to claim 25, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 29 (Currently Amended): A light emitting device having comprising:

a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, and an organic light emitting diode over a substrate,

a second capacitor storage over the first capacitor storage,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

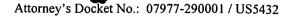
wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

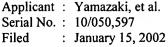
wherein the first capacitor storage has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer,

wherein the <u>second</u> capacitor storage has the capacitance electrode, the power supply line, and [[an]] <u>second</u> insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, and

wherein the connection wiring line overlaps an active layer of the switching thin film transistor.







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Claim 30 (Currently Amended): A light emitting device as claimed in any one of claim 29, wherein the insulating film is formed by anodization.

Claim 31 (Canceled)

Claim 32 (Original): An electric appliance comprising the light emitting device according to claim 29, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 33 (Currently Amended): A light emitting device having comprising:

a source line, a power supply line, a switching thin film transistor, and a driving thin film transistor over a substrate,

an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, and the driving thin film transistor,

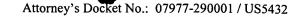
a capacitor storage <u>over the interlayer insulating film</u>, and an organic light emitting diode <u>over the interlayer insulating film</u>,

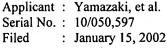
wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,







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wherein the capacitor storage has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, and

wherein a drain current of the driving thin film transistor is controlled by an analog video signal inputted to the source line and the drain current flows into the organic light emitting diode.

Claim 34 (Currently Amended): A light emitting device as claimed in any one of claim 33, wherein the insulating film is formed by anodization.

Claim 35 (Currently Amended): A light emitting device as claimed in any one of claim 33, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

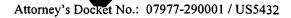
Claim 36 (Original): An electric appliance comprising the light emitting device according to claim 33, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

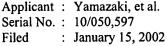
Claim 37 (Currently Amended): A light emitting device having comprising:
a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, and an organic light emitting diode over a substrate,

a second capacitor storage over the first capacitor storage,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,







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wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first capacitor storage has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer,

wherein the <u>second</u> capacitor storage has the capacitance electrode, the power supply line, and [[an]] <u>second</u> insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, and

wherein a drain current of the driving thin film transistor is controlled by an analog video signal inputted to the source line and the drain current flows into the organic light emitting diode.

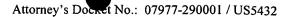
Claim 38 (Currently Amended): A light emitting device as claimed in any one of claim 37, wherein the insulating film is formed by anodization.

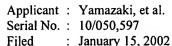
Claim 39 (Canceled)

Claim 40 (Original): An electric appliance comprising the light emitting device according to claim 37, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 41 (Currently Amended): A light emitting device having comprising:
a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, and a first capacitor storage over a substrate,







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an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, the driving thin film transistor, and the first capacitor,

a second capacitor storage <u>over the interlayer insulating film</u>, and an organic light emitting diode <u>over the interlayer insulating film</u>,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first capacitor storage has the connection wiring line, a capacitance wiring line, and a first insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second <u>first</u> capacitor storage has a capacitance electrode, a semiconductor layer, and a second <u>first</u> insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, and the semiconductor layer being formed at the same time active layers of the switching thin film transistor and the driving thin film transistor are formed, <u>and</u>

wherein the second capacitor storage has the connection wiring line, a capacitance wiring line, and a second insulating film formed between the connection wiring line and the capacitance wiring line.

Claim 42 (Currently Amended): A light emitting device as claimed in any one of claim 41, wherein the insulating film is formed by anodization.



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Claim 43 (Currently Amended): A light emitting device as claimed in any one of claim 41, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 44 (Original): An electric appliance comprising the light emitting device according to claim 41, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 45 (Original): A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, a second capacitor storage, and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

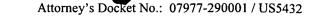
wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

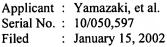
wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first capacitor storage has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second capacitor storage has a capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor.







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Claim 46 (Currently Amended): A light emitting device as claimed in any one of claim 45, wherein the insulating film is formed by anodization.

Claim 47 (Currently Amended): A light emitting device as claimed in any one of claim 45, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 48 (Original): An electric appliance comprising the light emitting device according to claim 45, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 49 (Currently Amended): A light emitting device having comprising:

a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, and a first capacitor storage over a substrate,

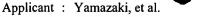
an interlayer insulating film over the source line, the power supply line, the switching transistor, the driving thin film transistor, and the first capacitor storage,

a second capacitor storage <u>over the interlayer insulating film</u>, and an organic light emitting diode <u>over the interlayer insulating film</u>,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,





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wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

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wherein the first capacitor storage has the connection wiring line, a capacitance wiring line, and a first insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second first capacitor storage has a capacitance electrode, a semiconductor layer, and a second first insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, the semiconductor layer being formed at the same time active layers of the switching thin film transistor and the driving thin film transistor are formed, [[and]]

wherein the second capacitor storage has the connection wiring line, a capacitance wiring line, and a second insulating film formed between the connection wiring line and the capacitance wiring line, and

wherein the connection wiring line overlaps the active layer of the switching thin film transistor.

Claim 50 (Currently Amended): A light emitting device as claimed in any one of claim 49, wherein the insulating film is formed by anodization.

Claim 51 (Currently Amended): A light emitting device as claimed in any one of claim 49, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 52 (Original): An electric appliance comprising the light emitting device according to claim 49, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile



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computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 53 (Original): A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, a second capacitor storage, and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

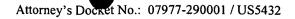
wherein the first capacitor storage has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line,

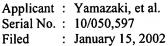
wherein the second capacitor storage has a capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor,

wherein the connection wiring line overlaps the active layer of the switching thin film transistor.

Claim 54 (Currently Amended): A light emitting device as claimed in any one of claim 53, wherein the insulating film is formed by anodization.







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Claim 55 (Currently Amended): A light emitting device as claimed in any one of claim 53, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 56 (Original): An electric appliance comprising the light emitting device according to claim 53, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 57 (Original): A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, a second capacitor storage, a third capacitor storage, and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

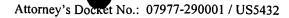
wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

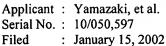
wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first capacitor storage has the connection wiring line, a capacitance wiring line, and a first insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second capacitor storage has a capacitance electrode, a semiconductor layer, and a second insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode







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of the driving thin film transistor, the semiconductor layer being formed at the same time active layers of the switching thin film transistor and the driving thin film transistor are formed,

wherein the third capacitor storage has the capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line.

Claim 58 (Currently Amended): A light emitting device as claimed in any one of claim 57, wherein the insulating film is formed by anodization.

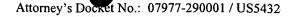
Claim 59 (Currently Amended): A light emitting device as claimed in any one of claim 57, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

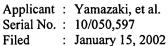
Claim 60 (Original): An electric appliance comprising the light emitting device according to claim 57, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

Claim 61 (Original): A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first capacitor storage, a second capacitor storage, a third capacitor storage, and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,





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wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first capacitor storage has the connection wiring line, a capacitance wiring line, and a first insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second capacitor storage has a capacitance electrode, a semiconductor layer, and a second insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, the semiconductor layer being formed at the same time active layers of the switching thin film transistor and the driving thin film transistor are formed,

wherein the third capacitor storage has the capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line, and

wherein the connection wiring line overlaps the active layer of the switching thin film transistor.

Claim 62 (Currently Amended): A light emitting device as claimed in any one of claim 61, wherein the insulating film is formed by anodization.

Claim 63 (Currently Amended): A light emitting device as claimed in any one of claim 61, wherein the connection capacitance wiring line and the pixel electrode are formed from the same conductive film.

Claim 64 (Original): An electric appliance comprising the light emitting device according to claim 61, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.



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Claim 65 (Currently Amended): A light emitting device comprising:

a plurality of pixels each having a thin film transistor and a capacitor storage,

wherein all of capacitor storages of the plurality of pixels share one capacitance wiring line, the capacitance wiring line formed on a different layer from a gate electrode of the thin film transistor,

wherein each of capacitor storages of the plurality of pixels has a connection wiring line, the capacitance wiring line, and an insulating film, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode of the thin film transistor, the an insulating film being formed between the connection wiring line and the one capacitance wiring line,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor, and

wherein the one capacitance wiring line overlaps an active layer of the thin film transistor of each of the plurality of pixels.

Claim 66 (Currently Amended): A light emitting device as claimed in any one of claim 65, wherein the insulating film is formed by anodization.

Claim 67 (Currently Amended): A light emitting device as claimed in any one of claim 65, wherein the connection capacitance wiring line and [[the]] a pixel electrode are formed from the same conductive film.

Claim 68 (Original): An electric appliance comprising the light emitting device according to claim 65, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

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